

**1.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER**
**Features**

- Glass Passivated Die Construction for High Reliability
- Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Ideally Suited for Automated Assembly
- Very High Reverse Breakdown Voltage
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

**Mechanical Data**

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead-Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (e3)
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.064 grams (Approximate)



Top View

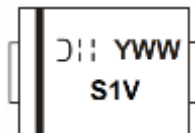


Bottom View

**Ordering Information** (Note 4)

| Part Number | Qualification | Case | Packaging         |
|-------------|---------------|------|-------------------|
| S1V-13-F    | Commercial    | SMA  | 5,000/Tape & Reel |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**


S1V = Product Type Marking Code  
 = Manufacturers' Code Marking  
 YWW = Date Code Marking  
 Y = Last Digit of Year (ex: 7 for 2017)  
 WW = Week Code (01 to 53)

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

| Characteristic                                                                                      | Symbol              | Value | Unit             |
|-----------------------------------------------------------------------------------------------------|---------------------|-------|------------------|
| Peak Repetitive Reverse Voltage                                                                     | V <sub>RRM</sub>    | 2,000 | V                |
| Working Peak Reverse Voltage                                                                        | V <sub>RWM</sub>    |       |                  |
| DC Blocking Voltage                                                                                 | V <sub>R</sub>      |       |                  |
| RMS Reverse Voltage                                                                                 | V <sub>R(RMS)</sub> | 1400  | V                |
| Average Rectified Output Current @ T <sub>T</sub> = +100°C                                          | I <sub>O</sub>      | 1.0   | A                |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed on Rated Load | I <sub>FSM</sub>    | 30    | A                |
| I <sup>2</sup> t Rating for Fusing (t < 8.3ms)                                                      | I <sup>2</sup> t    | 3.74  | A <sup>2</sup> S |

## Thermal Characteristics

| Characteristic                                           | Symbol                            | Value       | Unit |
|----------------------------------------------------------|-----------------------------------|-------------|------|
| Typical Thermal Resistance, Junction to Ambient (Note 5) | R <sub>θJA</sub>                  | 50          | °C/W |
| Operating and Storage Temperature Range                  | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                           | Symbol             | Min   | Typ | Max | Unit |
|----------------------------------------------------------|--------------------|-------|-----|-----|------|
| Reverse Breakdown Voltage(Note 7) @ I <sub>R</sub> = 5μA | V <sub>(BR)R</sub> | 2,000 | —   | —   | V    |
| Forward Voltage @ I <sub>F</sub> = 1.0A                  | V <sub>F</sub>     | —     | 1.0 | 1.3 | V    |
| Peak Reverse Leakage Current @ T <sub>A</sub> = +25°C    | I <sub>R</sub>     | —     | 0.2 | 5.0 | μA   |
| at Rated DC Blocking Voltage @ T <sub>A</sub> = +125°C   |                    | —     | 37  | 100 |      |
| Typical Total Capacitance (Note 6)                       | C <sub>T</sub>     | —     | 4   | —   | pF   |

Notes: 5. Thermal resistance junction to ambient at 0.375 inch (9.5mm) lead length.  
6. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
7. Short duration pulse test used to minimize self-heating effect.

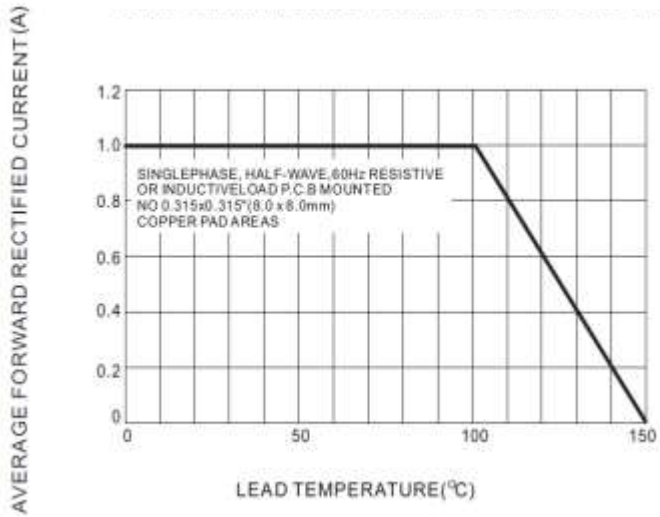


Figure 1 Maximum Average Forward Current Derating

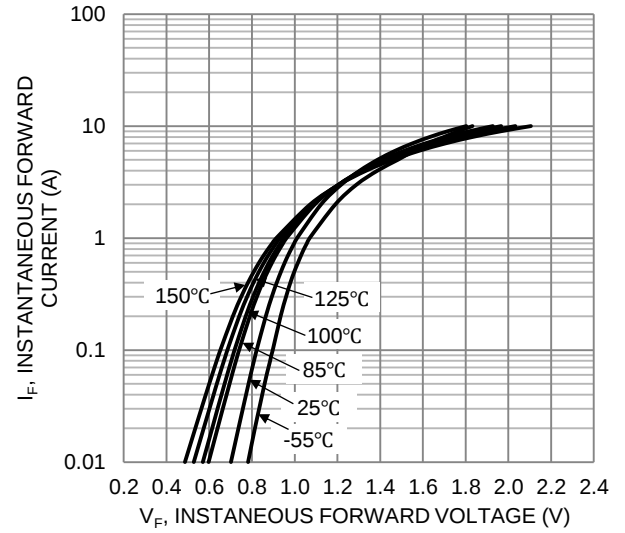


Figure 2 Typical Forward Characteristics

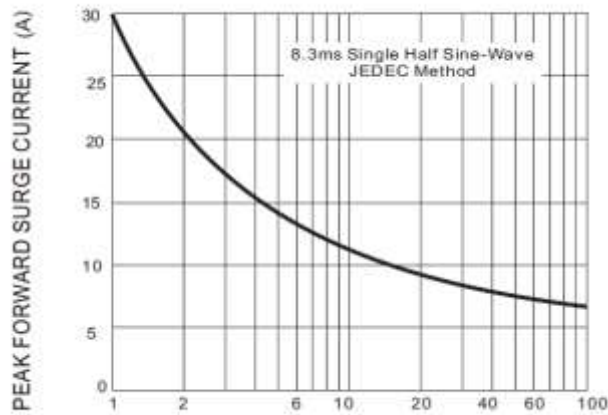


Figure 3 Maximum Non-Repetitive Surge Current

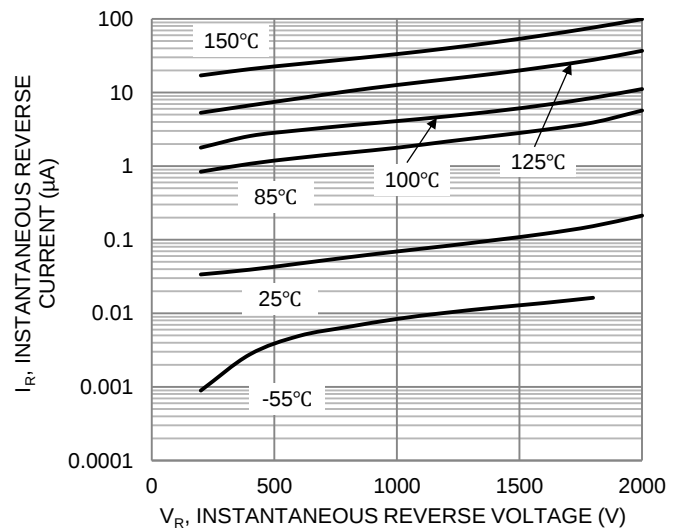


Figure 4 Typical Reverse Characteristics

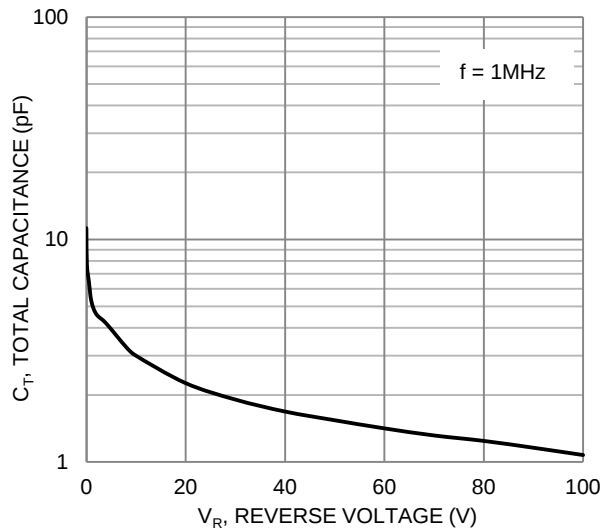
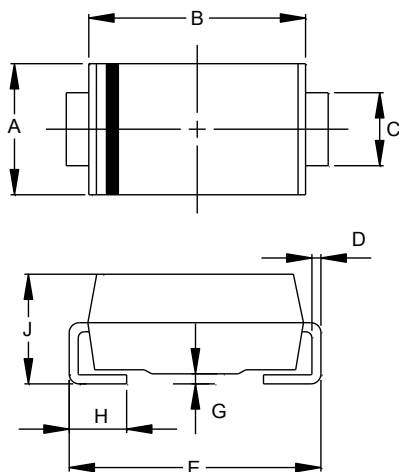


Figure 5 Typical Total Capacitance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SMA

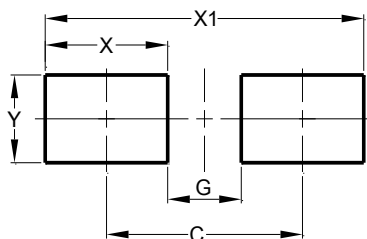


| SMA                  |      |      |
|----------------------|------|------|
| Dim                  | Min  | Max  |
| A                    | 2.29 | 2.92 |
| B                    | 4.00 | 4.60 |
| C                    | 1.27 | 1.63 |
| D                    | 0.15 | 0.31 |
| E                    | 4.80 | 5.59 |
| G                    | 0.05 | 0.20 |
| H                    | 0.76 | 1.52 |
| J                    | 1.96 | 2.40 |
| All Dimensions in mm |      |      |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SMA



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 4.00          |
| G          | 1.50          |
| X          | 2.50          |
| X1         | 6.50          |
| Y          | 1.70          |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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